

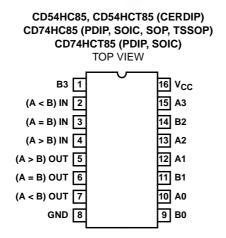
Data sheet acquired from Harris Semiconductor SCHS136E

August 1997 - Revised October 2003

Features

- Buffered Inputs and Outputs
- Typical Propagation Delay: 13ns (Data to Output at V_{CC} = 5V, C_L = 15pF, T_A = 25^oC
- Serial or Parallel Expansion Without External Gating
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, I_I \leq 1µA at V_{OL}, V_{OH}

Pinout



CD54HC85, CD74HC85, CD54HCT85, CD74HCT85

High-Speed CMOS Logic 4-Bit Magnitude Comparator

Description

The 'HC85 and 'HCT85 are high speed magnitude comparators that use silicon-gate CMOS technology to achieve operating speeds similar to LSTTL with the low power consumption of standard CMOS integrated circuits.

These 4-bit devices compare two binary, BCD, or other monotonic codes and present the three possible magnitude results at the outputs (A > B, A < B, and A = B). The 4-bit input words are weighted (A0 to A3 and B0 to B3), where A3 and B₃ are the most significant bits.

The devices are expandable without external gating, in both serial and parallel fashion. The upper part of the truth table indicates operation using a single device or devices in a serially expanded application. The parallel expansion scheme is described by the last three entries in the truth table.

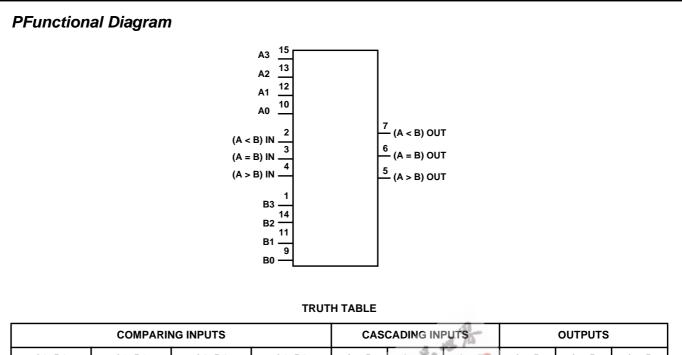
Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD54HC85F3A	-55 to 125	16 Ld CERDIP
CD54HCT85F3A	-55 to 125	16 Ld CERDIP
CD74HC85E	-55 to 125	16 Ld PDIP
CD74HC85M	-55 to 125	16 Ld SOIC
CD74HC85MT	-55 to 125	16 Ld SOIC
CD74HC85M96	-55 to 125	16 Ld SOIC
CD74HC85NSR	-55 to 125	16 Ld SOP
CD74HC85PW	-55 to 125	16 Ld TSSOP
CD74HC85PWR	-55 to 125	16 Ld TSSOP
CD74HC85PWT	-55 to 125	16 Ld TSSOP
CD74HCT85E	-55 to 125	16 Ld PDIP
CD74HCT85M	-55 to 125	16 Ld SOIC
CD74HCT85MT	-55 to 125	16 Ld SOIC
CD74HCT85M96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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	CONFARI	NG INFUIS	CAS			0012013			
A3, B3	A2, B2	A1, B1	A0, B0	A > B	A < B	A = B	A > B	A < B	A = B
SINGLE DEVIC	E OR SERIES C	ASCADING		. 36. 9	5	-			
A3 > B3	Х	Х	x	x	X	x	н	L	L
A3 < B3	Х	Х	X	Х	x	х	L	н	L
A3 = B3	A2 >B2	Х	×	×	х	х	н	L	L
A3 = B3	A2 < B2	Х	Х	x	х	х	L	н	L
A3 = B3	A2 = B2	A1 > B1	х	х	х	х	н	L	L
A3 = B3	A2 = B2	A1 < B1	Х	х	Х	х	L	н	L
A3 = B3	A2 = B2	A1 = B1	A0 > B0	Х	Х	х	Н	L	L
A3 = B3	A2 = B2	A1 = B1	A0 < B0	Х	Х	х	L	Н	L
A3 = B3	A2 = B2	A1 = B1	A0 = B0	Н	L	L	Н	L	L
A3 = B3	A2 = B2	A1 = B1	A0 = B0	L	Н	L	L	Н	L
A3 = B3	A2 = B2	A1 = B1	A0 = B0	L	L	н	L	L	Н
PARALLEL CA	SCADING								
A3 = B3	A2 = B2	A1 = B1	A0 = B0	Х	Х	Н	L	L	Н
A3 = B3	A2 = B2	A1 = B1	A0 = B0	Н	Н	L	L	L	L
A3 = B3	A2 = B2S	A1 = B1	A0 = B0	L	L	L	Н	Н	L

H = High Voltage Level, L = Low Voltage, Level, X = Don't Care

CD54HC85, CD74HC85, CD54HCT85, CD74HCT85

CD54HC85, CD74HC85, CD54HCT85, CD74HCT85

Absolute Maximum Ratings

DC Supply Voltage, V _{CC}
DC Input Diode Current, I _{IK}
For V _I < -0.5V or V _I > V _{CC} + 0.5V
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_0 > -0.5V$ or $V_0 < V_{CC} + 0.5V$
DC V _{CC} or Ground Current, I _{CC or} I _{GND} ±50mA
Operating Conditions

Operating Conditions

Temperature Range (T _A)55°C to 125°C
Supply Voltage Range, V _{CC}
HC Types
HCT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TE: CONDI	-	vcc		25°C			O 85 ⁰ C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	VIH		-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input V _{IL} Voltage	-	-	2	-	-	0.5	-	0.5	-	0.5	V	
			4.5	-	-	1.35	-	1.35	-	1.35	V	
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V	
Voltage CMOS Loads	lds		-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
CIVIOS LUaus			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output		-	-	-	-	-	-	-	-	-	V	
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
TTE EDaus			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
CIVIOS LUdus			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	ICC	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ

		TEST CONDITIONS		Vcc	25 ⁰ C			-40 ^o C TO 85 ^o C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	l _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	VIL	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	2	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} and GND	0	5.5	-	. 3	±0.1		±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	3	3	8		80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I _{CC} (Note 2)	V _{CC} -2.1		4.5 to 5.5	-	100	360	-	450	-	490	μA

CD54HC85, CD74HC85, CD54HCT85, CD74HCT85

2. For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
A0-A3, B0-B3 and (A = B) IN	1.5
(A > B) IN, (A < B) IN	1

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g. 360µA max at 25°C.

Switching Specifications Input t_{f} , t_{f} = 6ns

		TEST			25 ⁰ C		-	с то °С		С ТО 5°С	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-					-				-	-
Propagation Delay,	t _{PLH} , t _{PHL}	$C_L = 50 pF$	2	-	-	195	-	245	-	295	ns
A _n , B _n to (A > B) OUT, (A < B) OUT			4.5	-	-	39	-	47	-	59	ns
(A < B) 001		C _L = 15pF	5	-	16	-	-	-	-	-	ns
		$C_L = 50 pF$	6	-	-	33	-	42	-	50	ns
A_n , B_n to (A = B) OUT	t _{PLH} , t _{PHL}	$C_L = 50 pF$	2	-	-	175	-	240	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		$C_L = 50 pF$	6	-	-	30	-	37	-	45	ns

CD54HC85, CD74HC85, CD54HCT85, CD74HCT85

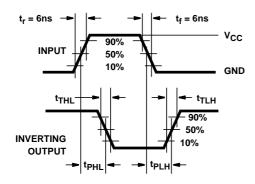
		TEST			25 ⁰ C			сто °C	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
(A > B) IN, (A < B) IN, (A = B) IN	tPLH, tPHL	C _L = 50pF	2	-	-	140	-	175	-	210	ns
to $(A > B)$ OUT, $(A < B)$ OUT			4.5	-	-	28	-	35	-	42	ns
		C _L = 15pF	5	-	11	-	-	-	-	-	ns
		$C_L = 50 pF$	6	-	-	24	-	30	-	36	ns
(A > B) IN to $(A = B)$ OUT	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	120	-	150	-	180	ns
			4.5	-	-	24	-	30	-	36	ns
		C _L = 15pF	5	-	9	-	-	-	-	-	ns
		$C_L = 50 pF$	6	-	-	20	-	26	-	31	ns
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	24	-	-	-	-	-	pF
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C _{IN}	-	-	-	-	10	a -	10	-	10	pF
HCT TYPES						J.	10				
Propagation Delay,	t _{PLH} , t _{PHL}	$C_L = 50 pF$	4.5	- /	36	37		46	-	56	ns
An, Bn to $(A > B)$ OUT, (A < B) OUT		C _L = 15pF	5	a 9	15			-	-	-	ns
An, Bn to (A = B) OUT	t _{PLH} , t _{PHL}		4.5	91. -		40	-	50	-	60	ns
		C _L = 15pF	5	(17	-	-	-	-	-	ns
(A > B) IN, $(A < B)$ IN, $(A = B)$ IN	t _{PLH} , t _{PHL}	$C_L = 50 pF$	4.5	-	-	30	-	38	-	45	ns
to $(A > B)$ OUT, $(A < B)$ OUT		C _L = 15pF	5	-	12	-	-	-	-	-	ns
(A > B) IN to $(A = B)$ OUT	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	31	-	39	-	47	ns
		$C_L = 15 pF$	5	-	13	-	-	-	-	-	ns
Output Transition Times (Figure 1)	t _{TLH} , t _{THL}	$C_L = 50 pF$	4.5	-	-	15	-	19	-	22	ns
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	26	-	-	-	-	-	pF
Input Capacitance	CIN	-	-	-	-	10	-	10	-	10	pF

NOTES:

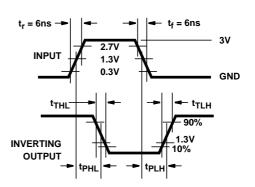
3. $C_{\mbox{PD}}$ is used to determine the dynamic power consumption, per gate/package.

4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where $f_i =$ Input Frequency, $C_L =$ Output Load Capacitance, $V_{CC} =$ Supply Voltage.

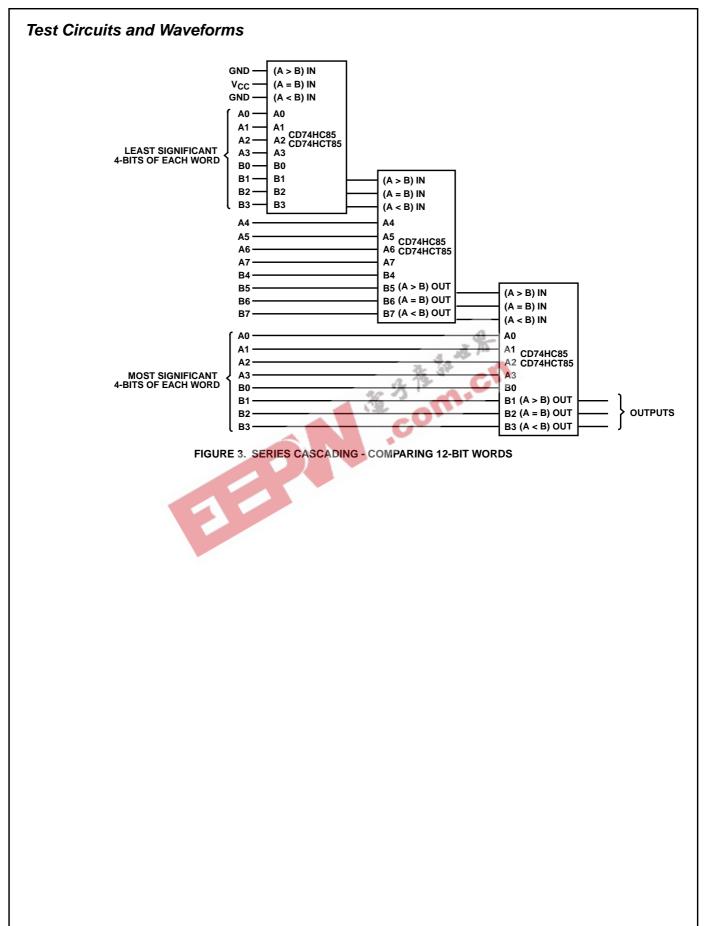
Test Circuits and Waveforms



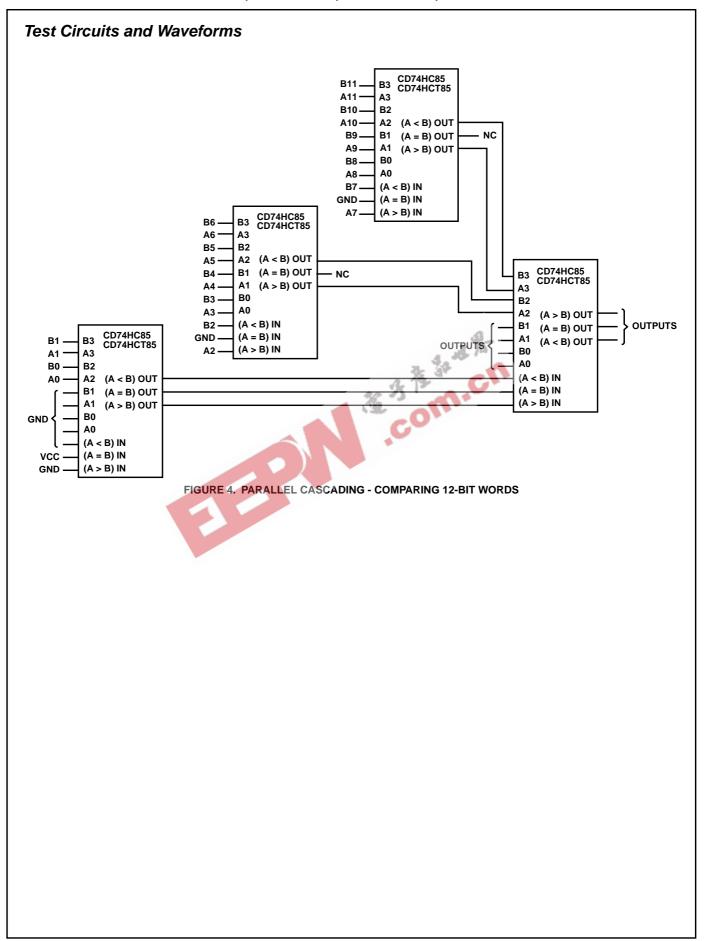








CD54HC85, CD74HC85, CD54HCT85, CD74HCT85





PACKAGE OPTION ADDENDUM

9-Oct-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-8867201EA	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
8601301EA	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC85F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT85F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC85E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC85EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC85M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85NSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85NSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85NSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85PWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85PWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85PWT	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85PWTE4	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC85PWTG4	ACTIVE	TSSOP	PW	16	250	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

9-Oct-2007

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
						no Sb/Br)		
CD74HCT85E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT85EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT85M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT85M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT85M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT85M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT85ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT85MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT85MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT85MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT85MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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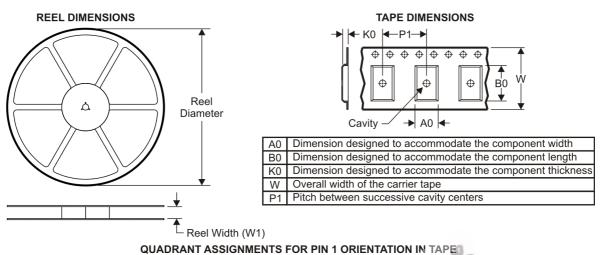
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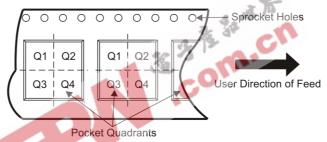


PACKAGE MATERIALS INFORMATION

19-Mar-2008

TAPE AND REEL INFORMATION



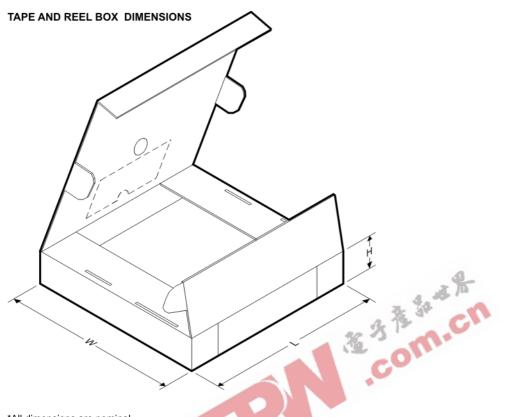


*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadra
CD74HC85M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC85NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC85PWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
CD74HCT85M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

19-Mar-2008



*All dimensions are nominal

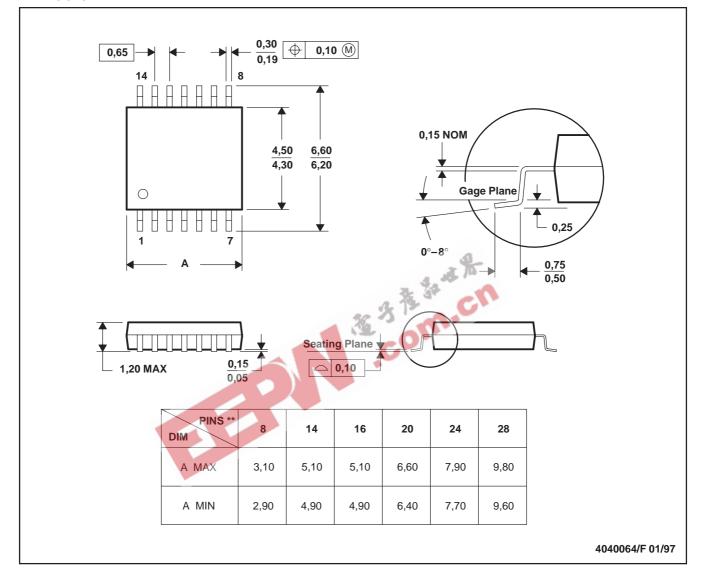
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC85M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HC85NSR	SO	NS	16	2000	346.0	346.0	33.0
CD74HC85PWR	TSSOP	PW	16	2000	346.0	346.0	29.0
CD74HCT85M96	SOIC	D	16	2500	333.2	345.9	28.6

MECHANICAL DATA

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

PLASTIC SMALL-OUTLINE PACKAGE

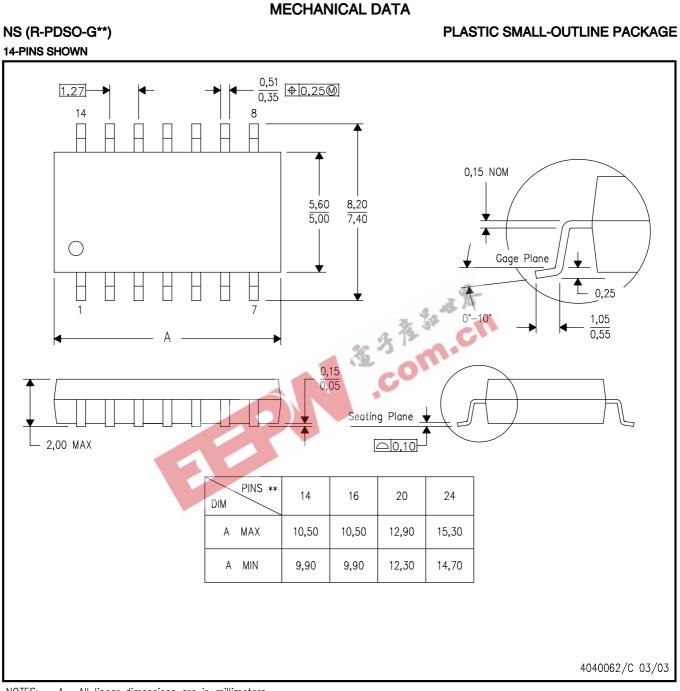




NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE

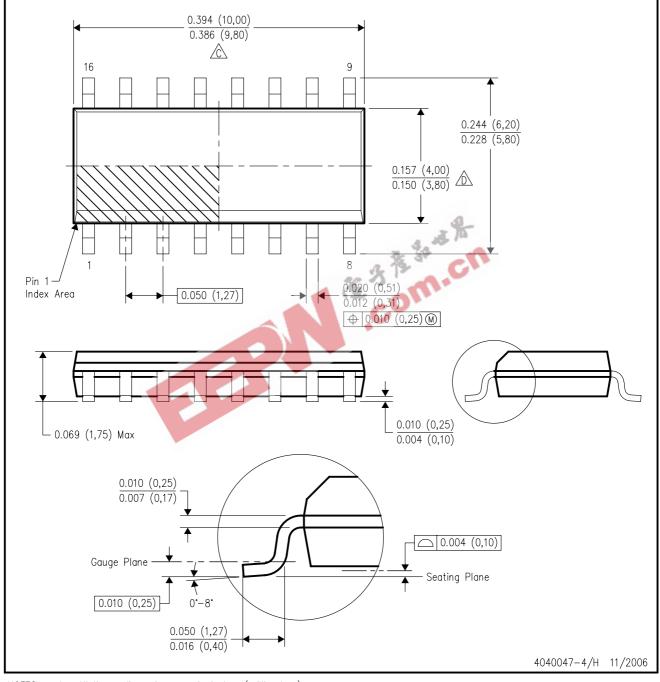
PINS ** 14 16 18 20 DIM 0.300 0.300 0.300 0.300 В А (7,62) (7,62) (7,62) (7,62) BSC BSC BSC BSC 8 14 0.785 1.060 .840 0.960 B MAX (19,94)(21, 34)(24, 38)(26, 92)B MIN С 0.300 0.300 0.310 0.300 C MAX (7, 62)(7,62) (7, 62)(7, 87)C MIN 7 0.245 0.245 0.220 0.245 0.065 (1,65) 0.045 (1,14) (6, 22)(6, 22)(5, 59)(6, 22)0.060 (1,52) - 0.005 (0,13) MIN Α -0.015 (0,38) 0.200 (5,08) MAX Seating Plane 0.130 (3,30) MIN 0.026 (0,66) 0.014 (0,36) 0°-15° 0.100 (2,54) 0.014 (0,36) 0.008 (0,20) 4040083/F 03/03

NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

D (R-PDSO-G16)

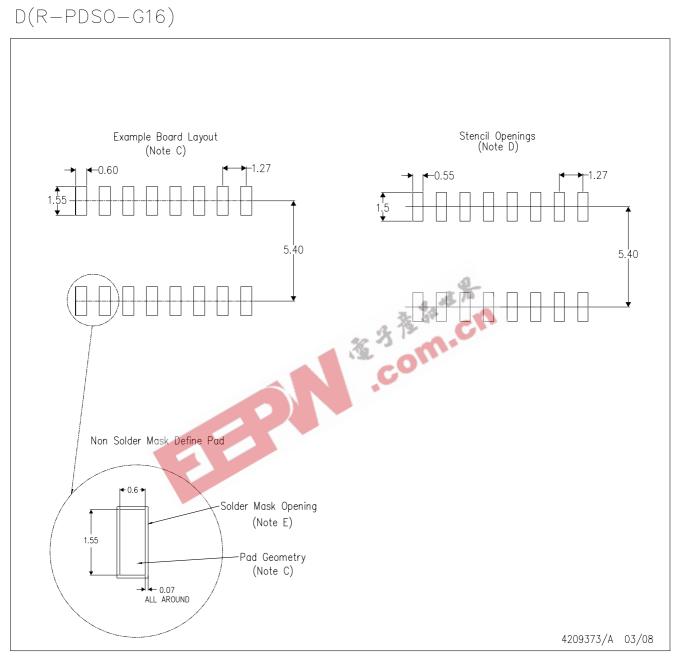
PLASTIC SMALL-OUTLINE PACKAGE



All linear dimensions are in inches (millimeters). NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- 🖄 Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side. E. Reference JEDEC MS-012 variation AC.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.

- \triangle Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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